

Symbol	Parameter		Ratings	Units	
V <sub>DSS</sub>	Drain to Source Voltage		40	V	
V <sub>GS</sub>	Gate to Source Voltage		±20	V	
	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> =25°C	110	٨	
I <sub>D</sub>	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure4	Α	
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	174	mJ	
P <sub>D</sub>	Power Dissipation		176	W	
	Derate above 25°C		1.18	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.85	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB9406	FDB9406-F085	D2-PAK(TO-263)	330mm	24mm	800 units

#### Notes:

1: Current is limited by bondwire configuration. 2: Starting  $T_J = 25^{\circ}$ C, L = 0.045mH, I<sub>AS</sub> = 88A, V<sub>DD</sub> = 40V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche. 3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder

mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Cha	racteristics					
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	$I_{D}$ = 250µA, $V_{GS}$ = 0V	40	-	-	V
<b>I</b>	Drain-to-Source Leakage Current	$V_{DS}$ =40V, $T_{J}$ =25°C	-	-	1	μA
IDSS	Diam-to-Source Leakage Current	$V_{GS} = 0V$ $T_{J} = 175^{\circ}C(Note 4)$	-	-	1	mA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA
R <sub>DS(on)</sub>	Drain-to-Source On Resistance	$I_{\rm D} = 80A, \qquad T_{\rm J} = 25^{\circ}C$	-	1.31	1.8	mΩ
V <sub>GS(th)</sub>	Gate-to-Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2.0	2.83	4.0	V
R <sub>DS(on)</sub>	Drain-to-Source On Resistance	$V_{GS} = 10V$ $T_J = 175^{\circ}C(Note 4)$	_	2.2	2.8	mΩ
C <sub>iss</sub>	c Characteristics		-	7710	-	pF
C <sub>oss</sub>	Output Capacitance	f = 1MHz	-	2015	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		-	140	-	pF
R <sub>g</sub>	Gate Resistance	f = 1MHz	-	2.7	-	Ω
Q <sub>g(ToT)</sub>	Total Gate Charge at 10V	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 32V$	-	107	138	nC
				14	19	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 2V$ $I_D = 80A$	-		19	no
Q <sub>g(th)</sub> Q <sub>gs</sub>	Threshold Gate Charge Gate-to-Source Gate Charge	$V_{GS} = 0$ to 2V $I_D = 80A$	-	33	-	nC

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# **Switching Characteristics**

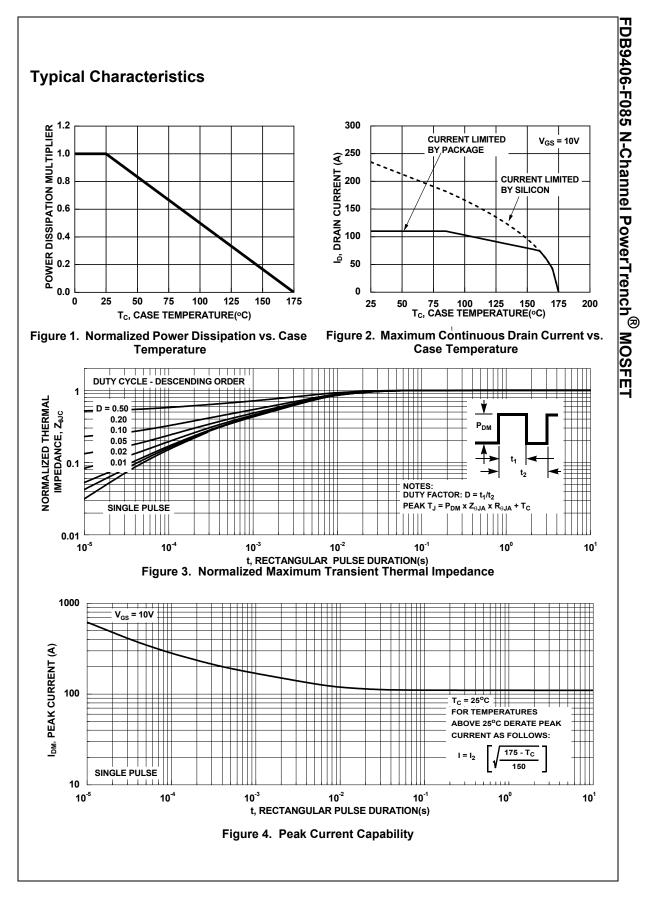
t <sub>on</sub>	Turn-On Time		-	-	160	ns
t <sub>d(on)</sub>	Turn-On Delay		-	32	-	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 20V, I <sub>D</sub> = 80A,	-	81	-	ns
t <sub>d(off)</sub>	Turn-Off Delay	$V_{DD}$ = 20V, I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V, R <sub>GEN</sub> = 6Ω	-	50	-	ns
t <sub>f</sub>	Fall Time		-	23	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	93	ns

## **Drain-Source Diode Characteristics**

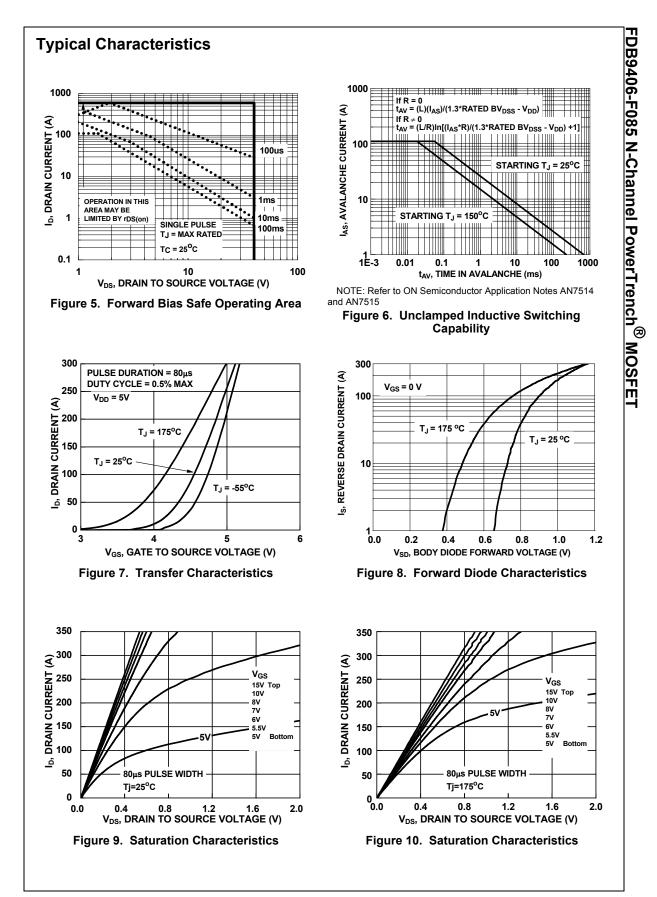
$V_{SD}$	Source-to-Drain Diode Voltage	I <sub>SD</sub> = 80A, V <sub>GS</sub> = 0V	-	-	1.25	V
t <sub>rr</sub>	Reverse-Recovery Time	$I_{F} = 80A, dI_{SD}/dt = 100A/\mu s,$	-	85	110	ns
Q <sub>rr</sub>	Reverse-Recovery Charge	V <sub>DD</sub> =32V	-	122	160	nC

Note:

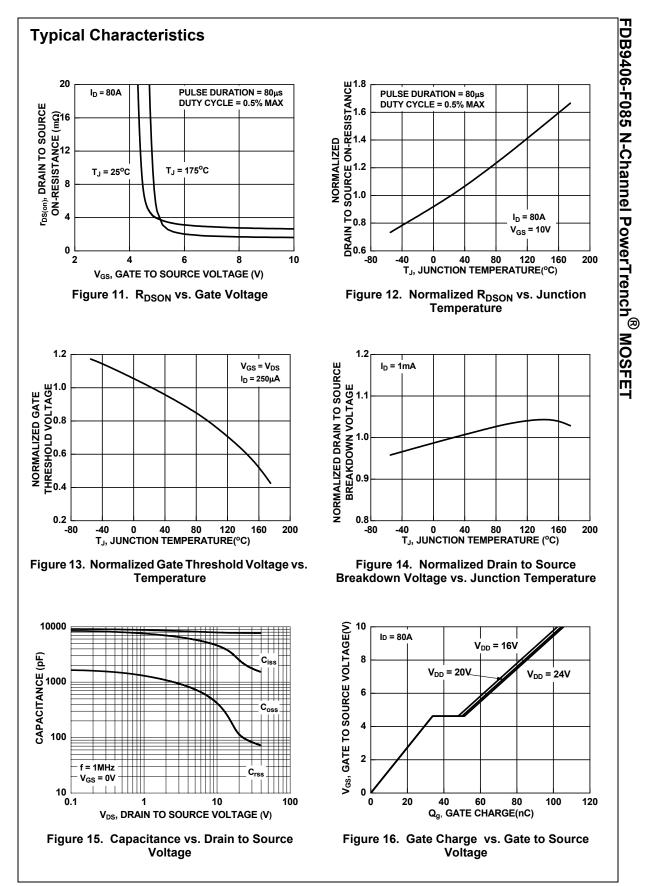
4: The maximum value is specified by design at  $T_J$  = 175°C. Product is not tested to this condition in production.



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